## NSN 5961-01-172-0915

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-172-0915 **Inclosure Material:** Plastic **Overall Length:** 0.205 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.210 inches **Overall Width:** 0.165 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -30.0 drain to gate voltage and -30.0 drain to source voltage and -30.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 80009-151-1097-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: